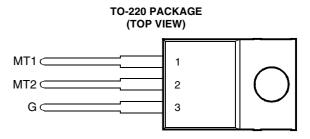
BOURNS®

- Sensitive Gate Triacs
- 2.5 A RMS
- Glass Passivated Wafer
- 400 V to 700 V Off-State Voltage
- Max I_{GT} of 5 mA (Quadrant 1)



Pin 2 is in electrical contact with the mounting base.

absolute maximum ratings over operating case temperature (unless otherwise noted)

RATING			VALUE	UNIT	
	TIC201D		400		
Repetitive peak off-state voltage (see Note 1)	TIC201M	V _{DRM}	600	V	
	TIC201S		700		
Full-cycle RMS on-state current at (or below) 85°C case temperature (see Note 2)			2.5	A	
Peak on-state surge current full-sine-wave at (or below) 25°C case temperature (see Note 3)			12	А	
Peak gate current			±0.2	А	
Peak gate power dissipation at (or below) 85°C case temperature (pulse width \leq 200 μ s)			1.3	W	
Average gate power dissipation at (or below) 85°C case temperature (see Note 4)			0.3	W	
Operating case temperature range			-40 to +110	°C	
Storage temperature range			-40 to +125	°C	
Lead temperature 1.6 mm from case for 10 seconds			230	°C	

NOTES: 1. These values apply bidirectionally for any value of resistance between the gate and Main Terminal 1.

2. This value applies for 50-Hz full-sine-wave operation with resistive load. Above 85°C derate linearly to 110°C case temperature at the rate of 100 mA/°C.

This value applies for one 50-Hz full-sine-wave when the device is operating at (or below) the rated value of on-state current. Surge
may be repeated after the device has returned to original thermal equilibrium. During the surge, gate control may be lost.

4. This value applies for a maximum averaging time of 20 ms.

electrical characteristics at 25°C case temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS			MIN	ТҮР	МАХ	UNIT
I _{DRM}	Repetitive peak off-state current	$V_{D} = rated V_{DRM}$	I _G = 0	T _C = 110°C			±1	mA
I _{GT}	Gate trigger current	$V_{supply} = +12 V†$ $V_{supply} = +12 V†$ $V_{supply} = -12 V†$ $V_{supply} = -12 V†$	RL = 10 Ω $RL = 10 Ω$ $RL = 10 Ω$ $RL = 10 Ω$ $RL = 10 Ω$	$t_{p(g)} > 20 \ \mu s$ $t_{p(g)} > 20 \ \mu s$ $t_{p(g)} > 20 \ \mu s$ $t_{p(g)} > 20 \ \mu s$			5 -8 -10 25	mA

† All voltages are with respect to Main Terminal 1.

PRODUCT INFORMATION



electrical characteristics at 25°C case temperature (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS			MIN	ТҮР	MAX	UNIT
		V _{supply} = +12 V†	$R_L = 10 \Omega$	t _{p(g)} > 20 μs		0.7	2.5	
V	Gate trigger	V _{supply} = +12 V†	$R_L = 10 \Omega$	t _{p(g)} > 20 μs		-0.7	-2.5	v
V _{GT}	voltage	$V_{supply} = -12 V^{\dagger}$	$R_L = 10 \Omega$	t _{p(g)} > 20 μs		-0.7	-2.5	v
		$V_{supply} = -12 V^{\dagger}$	$R_L = 10 \Omega$	t _{p(g)} > 20 μs		0.7		
V _T	On-state voltage	I _T = ±3.5 A	l _G = 50 mA	(see Note 5)			±1.9	V
Ι _Η	Holding current	V _{supply} = +12 V†	I _G = 0	Init' I _{TM} = 100 mA			30	mA
		$V_{supply} = -12 V^{\dagger}$	$I_{G} = 0$	Init' I _{TM} = - 100 mA			-30	
١ _L	Latching current	V _{supply} = +12 V†	(see Note 6)				40	mA
		$V_{supply} = -12 V^{\dagger}$				-40	IIIA	
dv/dt	Critical rate of rise of	V _{DBM} = Rated V _{DBM}	l _G = 0	T _C = 110°C		±20		V/µs
	off-state voltage	VDRM - Mated VDRM		1 _C = 110 0		120		•7µ3
dv/dt _(c)	Critical rise of	V — Botod V	I _{TRM} = ±3.5 A	T _C = 85°C	±1	±4		V/µs
	commutation voltage	VDRM - Maled VDRM		10 - 03 0	- <u>-</u> 1	14		v/µs

† All voltages are with respect to Main Terminal 1.

NOTES: 5. This parameter must be measured using pulse techniques, $t_p = \le 1$ ms, duty cycle ≤ 2 %. Voltage-sensing contacts separate from the current carrying contacts are located within 3.2 mm from the device body.

6. The triacs are triggered by a 15-V (open circuit amplitude) pulse supplied by a generator with the following characteristics: $R_G = 100 \Omega$, $t_{p(g)} = 20 \mu s$, $t_r = \le 15 ns$, f = 1 kHz.

thermal characteristics

PARAMETER			TYP	MAX	UNIT
$R_{\theta JC}$ Junction to case thermal resistance				10	°C/W
$R_{\theta JA}$ Junction to free air thermal resistance				62.5	°C/W

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Mouser Electronics

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